74HC1G04; 74HCT1G04

Inverter

Rev. 5 — 25 September 2013

Product data sheet

1. General description

The 74HC1G04; 74HCT1G04 is a single inverter. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
 - ◆ For 74HC1G04: CMOS level
 - ◆ For 74HCT1G04: TTL level
- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Ordering information

Table 1. Ordering information

| Type number | Package | | | | | | | |
|-------------|-------------------|--------|---|----------|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | |
| 74HC1G04GW | –40 °C to +125 °C | TSSOP5 | plastic thin shrink small outline package; 5 leads; | SOT353-1 | | | | |
| 74HCT1G04GW | | | body width 1.25 mm | | | | | |
| 74HC1G04GV | –40 °C to +125 °C | SC-74A | plastic surface-mounted package; 5 leads | SOT753 | | | | |
| 74HCT1G04GV | | | | | | | | |



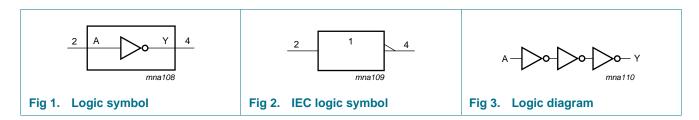
4. Marking

Table 2. Marking codes

| Type number | Marking[1] |
|-------------|------------|
| 74HC1G04GW | HC |
| 74HCT1G04GW | TC |
| 74HC1G04GV | H04 |
| 74HCT1G04GV | T04 |

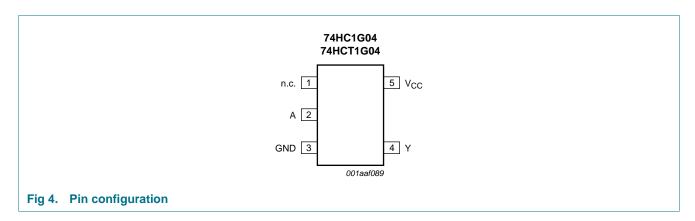
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

| Symbol | Pin | Description |
|-----------------|-----|----------------|
| n.c. | 1 | not connected |
| A | 2 | data input |
| GND | 3 | ground (0 V) |
| Υ | 4 | data output |
| V _{CC} | 5 | supply voltage |

74HC_HCT1G04

7. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level$

| Input | Output |
|-------|--------|
| A | Υ |
| L | Н |
| H | L |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V). [1]

| | | | | (9.00 | - , |
|------------------|-------------------------|---|-------|-------|------|
| Symbol | Parameter | Conditions | Min | Max | Unit |
| V_{CC} | supply voltage | | -0.5 | +7.0 | V |
| I _{IK} | input clamping current | $V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$ | - | ±20 | mA |
| I _{OK} | output clamping current | $V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$ | - | ±20 | mA |
| Io | output current | $-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$ | - | ±12.5 | mA |
| I _{CC} | supply current | | - | 25 | mA |
| I_{GND} | ground current | | -25 | - | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ | [2] _ | 200 | mW |

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | 74HC1G04 | | | 74HCT1G04 | | | Unit |
|------------------|--|--------------------------|----------|-----|----------|-----------|-----|----------|------|
| | | | Min | Тур | Max | Min | Тур | Max | |
| V_{CC} | supply voltage | | 2.0 | 5.0 | 6.0 | 4.5 | 5.0 | 5.5 | V |
| VI | input voltage | | 0 | - | V_{CC} | 0 | - | V_{CC} | V |
| Vo | output voltage | | 0 | - | V_{CC} | 0 | - | V_{CC} | V |
| T _{amb} | ambient temperature | | -40 | +25 | +125 | -40 | +25 | +125 | °C |
| Δt/ΔV | input transition rise and fall rate | $V_{CC} = 2.0 \text{ V}$ | - | - | 625 | - | - | - | ns/V |
| | | V _{CC} = 4.5 V | - | - | 139 | - | - | 139 | ns/V |
| | | V _{CC} = 6.0 V | - | - | 83 | - | - | - | ns/V |

^[2] Above 55 °C, the value of P_{tot} derates linearly with 2.5 mW/K.

10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V). All typical values are measured at T_{amb} = 25 °C.

| Symbol | Parameter | Conditions | -40 | –40 °C to +85 °C | | | -40 °C to +125 °C | |
|-----------------|-----------------------------|--|------|------------------|------|------|-------------------|----|
| | | | Min | Тур | Max | Min | Max | |
| For type | 74HC1G04 | | | | | | | |
| V_{IH} | HIGH-level input | V _{CC} = 2.0 V | 1.5 | 1.2 | - | 1.5 | - | V |
| | voltage | V _{CC} = 4.5 V | 3.15 | 2.4 | - | 3.15 | - | V |
| | | V _{CC} = 6.0 V | 4.2 | 3.2 | - | 4.2 | - | V |
| V_{IL} | LOW-level input | V _{CC} = 2.0 V | - | 8.0 | 0.5 | - | 0.5 | V |
| | voltage | V _{CC} = 4.5 V | - | 2.1 | 1.35 | - | 1.35 | V |
| | | V _{CC} = 6.0 V | - | 2.8 | 1.8 | - | 1.8 | V |
| V _{OH} | HIGH-level output | $V_I = V_{IH}$ or V_{IL} | | | | | | |
| | voltage | $I_O = -20 \mu A; V_{CC} = 2.0 V$ | 1.9 | 2.0 | - | 1.9 | - | V |
| | | $I_O = -20 \mu A; V_{CC} = 4.5 V$ | 4.4 | 4.5 | - | 4.4 | - | V |
| | | $I_O = -20 \mu A; V_{CC} = 6.0 V$ | 5.9 | 6.0 | - | 5.9 | - | V |
| | | $I_{O} = -2.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$ | 4.13 | 4.32 | - | 3.7 | - | V |
| | | $I_{O} = -2.6 \text{ mA}; V_{CC} = 6.0 \text{ V}$ | 5.63 | 5.81 | - | 5.2 | - | V |
| V_{OL} | LOW-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | | | |
| | | $I_O = 20 \mu A; V_{CC} = 2.0 V$ | - | 0 | 0.1 | - | 0.1 | V |
| | | $I_O = 20 \mu A$; $V_{CC} = 4.5 V$ | - | 0 | 0.1 | - | 0.1 | V |
| | | $I_O = 20 \mu A$; $V_{CC} = 6.0 \text{ V}$ | - | 0 | 0.1 | - | 0.1 | V |
| | | $I_O = 2.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$ | - | 0.15 | 0.33 | - | 0.4 | V |
| | | $I_O = 2.6 \text{ mA}; V_{CC} = 6.0 \text{ V}$ | - | 0.16 | 0.33 | - | 0.4 | V |
| l _l | input leakage current | $V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$ | - | - | 1.0 | - | 1.0 | μΑ |
| I _{CC} | supply current | $V_1 = V_{CC}$ or GND; $I_0 = 0$ A; $V_{CC} = 6.0 \text{ V}$ | - | - | 10 | - | 20 | μΑ |
| Cı | input capacitance | | - | 1.5 | - | - | - | pF |
| For type | 74HCT1G04 | | | | | | | |
| V _{IH} | HIGH-level input voltage | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | 2.0 | 1.6 | - | 2.0 | - | V |
| V_{IL} | LOW-level input voltage | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | - | 1.2 | 0.8 | - | 0.8 | V |
| V_{OH} | HIGH-level output | $V_I = V_{IH}$ or V_{IL} | | | | | | |
| | voltage | $I_{O} = -20 \mu A; V_{CC} = 4.5 V$ | 4.4 | 4.5 | - | 4.4 | - | V |
| | | $I_{O} = -2.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$ | 4.13 | 4.32 | - | 3.7 | - | V |
| V_{OL} | LOW-level output | $V_I = V_{IH}$ or V_{IL} | | | | | | |
| | voltage | $I_O = 20 \mu A$; $V_{CC} = 4.5 V$ | - | 0 | 0.1 | - | 0.1 | V |
| | | $I_O = 2.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$ | - | 0.15 | 0.33 | - | 0.4 | V |
| I _I | input leakage current | $V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$ | - | - | 1.0 | - | 1.0 | μΑ |

 Table 7.
 Static characteristics ...continued

Voltages are referenced to GND (ground = 0 V). All typical values are measured at T_{amb} = 25 °C.

| Symbol Parameter | | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|------------------|---------------------------|---|------------------|-----|-----|-------------------|-----|------|
| | | | Min | Тур | Max | Min | Max | |
| I _{CC} | supply current | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$ | - | - | 10 | - | 20 | μΑ |
| ΔI_{CC} | additional supply current | per input; $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V};$ $V_{I} = V_{CC} - 2.1 \text{ V}; I_{O} = 0 \text{ A}$ | - | - | 500 | - | 850 | μΑ |
| Cı | input capacitance | | - | 1.5 | - | - | - | pF |

11. Dynamic characteristics

Table 8. Dynamic characteristics

GND = 0 V; $t_r = t_f \le 6.0$ ns; All typical values are measured at $T_{amb} = 25$ °C. For test circuit, see <u>Figure 6</u>

| Symbol | Parameter | Conditions | | -40 | °C to +8 | 5 °C | -40 °C to +125 °C | | Unit |
|-----------------|-------------------------------|--|------------|------------|----------|------|-------------------|-----|------|
| | | | | Min | Тур | Max | Min | Max | |
| For type | 74HC1G04 | | ' | | | | ' | ' | |
| t _{pd} | propagation delay | A to Y; see Figure 5 | <u>[1]</u> | | | | | | |
| | | $V_{CC} = 2.0 \text{ V}; C_L = 50 \text{ pF}$ | | - | 25 | 105 | - | 135 | ns |
| | | $V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$ | | - | 9 | 21 | - | 27 | ns |
| | | $V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$ | | - | 7 | - | - | - | ns |
| | | $V_{CC} = 6.0 \text{ V}; C_L = 50 \text{ pF}$ | | - | 8 | 18 | - | 23 | ns |
| C_{PD} | power dissipation capacitance | $V_I = GND$ to V_{CC} | [2] | - | 16 | - | - | - | pF |
| For type | 74HCT1G04 | | | | | | | | |
| t _{pd} | propagation delay | A to Y; see Figure 5 | <u>[1]</u> | | | | | | |
| | | $V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$ | | - | 10 | 24 | - | 27 | ns |
| | | $V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$ | | - | 8 | - | - | - | ns |
| C_{PD} | power dissipation capacitance | $V_I = GND \text{ to } V_{CC} - 1.5 \text{ V}$ | [2] | - | 18 | - | - | - | pF |

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz

f_o = output frequency in MHz

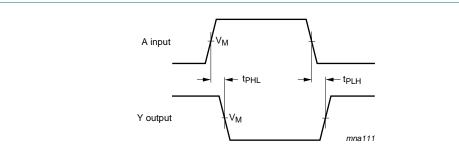
C_L = output load capacitance in pF

V_{CC} = supply voltage in Volts

 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs

^[2] C_{PD} is used to determine the dynamic power dissipation P_D (μW).

12. Waveforms

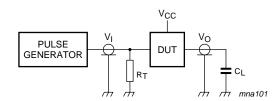


Measurement points are given in Table 9.

Fig 5. The input (A) to output (Y) propagation delays

Table 9. Measurement points

| Туре | V _I | V _M |
|-----------|------------------------|---------------------|
| 74HC1G04 | GND to V _{CC} | $0.5 \times V_{CC}$ |
| 74HCT1G04 | GND to 03 V | 1.3 V |



Test data is given in Table 8. Definitions for test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator

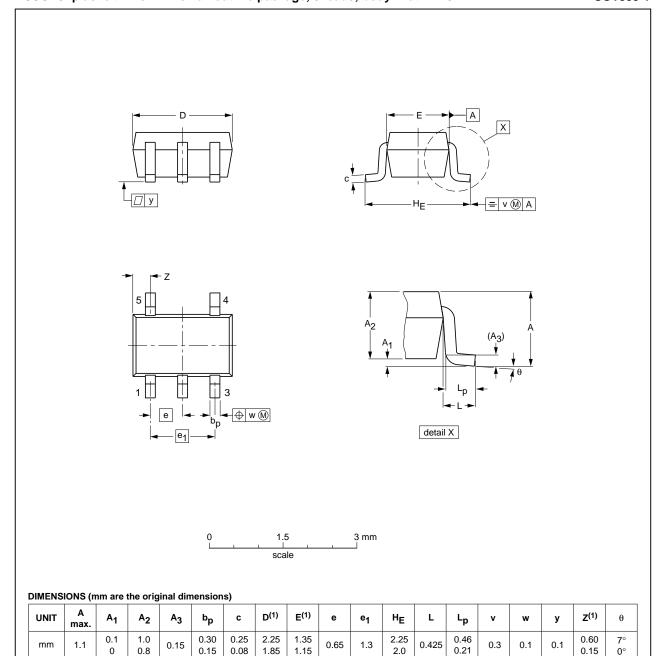
C_L = Load capacitance including jig and probe capacitance

Fig 6. Load circuitry for switching times

13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

| OUTLINE | | REFERENCES | | | REFERENCES EUROPEAN | | | |
|----------|-----|------------|--------|--|---------------------|----------------------------------|--|--|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE | | |
| SOT353-1 | | MO-203 | SC-88A | | | -00-09-01 03-02-19 | | |

Fig 7. Package outline SOT353-1 (TSSOP5)

74HC_HCT1G04

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Plastic surface-mounted package; 5 leads

SOT753

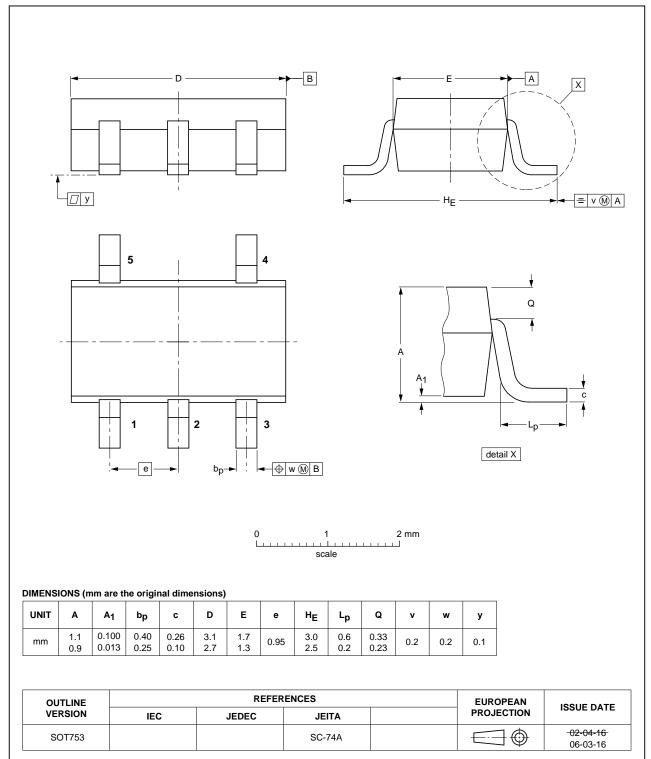


Fig 8. Package outline SOT753 (SC-74A)

14. Abbreviations

Table 10. Abbreviations

| Acronym | Description |
|---------|-----------------------------|
| DUT | Device Under Test |
| TTL | Transistor-Transistor Logic |

15. Revision history

Table 11. Revision history

| | • | | | | | |
|------------------|---|-------------------------------|---------------|------------------|--|--|
| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
| 74HC_HCT1G04 v.5 | 20130925 | Product data sheet | - | 74HC_HCT1G04 v.4 | | |
| Modifications: | Section 1 " | General description" updated. | | | | |
| 74HC_HCT1G04 v.4 | 20070716 | Product data sheet | - | 74HC_HCT1G04 v.3 | | |
| Modifications: | The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. | | | | | |
| | Legal texts have been adapted to the new company name where appropriate. | | | | | |
| | Package SOT353 changed to SOT353-1 in <u>Table 1</u> and <u>Figure 7</u>. | | | | | |
| | Quick Reference Data and Soldering sections removed. | | | | | |
| | Section 2 "Features and benefits" updated. | | | | | |
| 74HC_HCT1G04 v.3 | 20020517 | Product specification | - | 74HC_HCT1G04 v.2 | | |
| 74HC_HCT1G04 v.2 | 20010302 | Product specification | - | 74HC_HCT1G04 v.1 | | |
| 74HC_HCT1G04 v.1 | 19980831 | Preliminary specification | - | - | | |
| | | | | | | |

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|--------------------------------|-------------------|---|
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